











**TPS22960** 

SLVS914D - APRIL 2009-REVISED FEBRUARY 2016

# TPS22960 Low-Input Voltage, Dual-Load Switch With Controlled Turnon

## **Features**

- Integrated Dual-Load Switch
- Input Voltage Range: 1.62 V to 5.5 V
- Low ON-State Resistance
  - $r_{ON} = 342 \text{ m}\Omega \text{ at } V_{IN} = 5.5 \text{ V}$
  - r<sub>ON</sub> = 435 mΩ at V<sub>IN</sub> = 3.3 V
  - $r_{ON} = 523 \text{ m}\Omega \text{ at } V_{IN} = 2.5 \text{ V}$
  - $r_{ON} = 737 \text{ m}\Omega$  at  $V_{IN} = 1.8 \text{ V}$
- 500-mA Maximum Continuous Switch Current
- Low Quiescent Current and Shutdown Current
- Controlled Switch Output Rise Time: 75 µs or 660 µs
- Integrated Quick Output Discharge Transistor
- ESD Performance Tested Per JESD 22
  - 2000-V Human Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- 8-Pin SOT (DCN) Package: 3 mm x 3 mm
- 8-Pin UQFN (RSE) Package: 1.5 mm x 1.5 mm

# **Applications**

- **GPS Devices**
- Cell Phones/PDAs
- MP3 Players
- **Digital Cameras**

## 3 Description

The TPS22960 is a small low- $r_{\text{ON}}$  dual-channel load switch with controlled turnon. The devices contain two P-channel MOSFETs that can operate over an input voltage range of 1.62 V to 5.5 V. Each switch is independently controlled by on/off inputs (ON1 and ON2), which are capable of interfacing directly with low-voltage control signals. In TPS22960 a 85- $\Omega$  onchip load resistor is added for quick discharge when the switch is turned off.

The rise time (slew-rate) of the device is internally controlled in order to avoid inrush current, and it can be slowed down if needed using the SR pin: at 3.3 V. TPS22960 features a 75-us rise time with the SR pin tied to ground and 660-us with the SR pin tied to

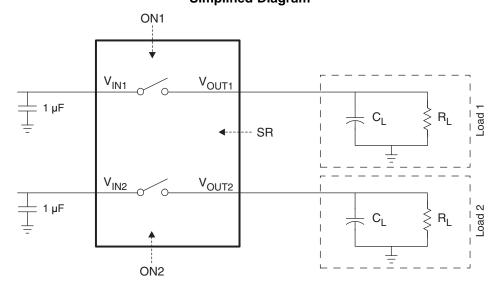
The TPS22960 is available in a space-saving 8-pin UQFN package and in an 8-pin SOT package. It is characterized for operation over the free-air temperature range of -40°C to 85°C.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TDC22060	SOT (8)	2.90 mm x 1.63 mm
TPS22960	UQFN (8)	1.50 mm × 1.50 mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.

# Simplified Diagram



Page



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# 4 Revision History

Changes from Revision C (July 2015) to Revision D

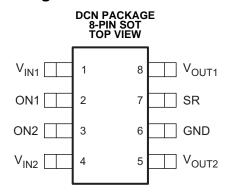
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

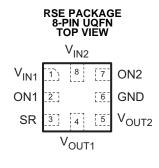
<u>.</u>	Made changes to Application Information	1
CI	hanges from Revision B (August 2013) to Revision C	Page
•	Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section	1
•	Updated the <i>Thermal Information</i> table to remove 220°C/W and 116°C/W from the junction-to-ambient thermal resistance, and 123°C/W and 60°C/W from the junction-to-case (top) thermal resistance	4
•	Changed values > 100°C/W in the <i>Thermal Information</i> table to contain only 3 significant figures	4
CI	hanges from Revision A (August 2011) to Revision B	Page
•	Clarified text in the <i>Description</i>	1
•	Added T <sub>J</sub> to the <i>Absolute Maximum Ratings</i> table	3
<u>•</u>	Updated Table 2 in <i>Device Functional Modes</i>	13
CI	hanges from Original (April 2009) to Revision A	Page
•	Changed r <sub>ON</sub> values for V <sub>INX</sub> = 1.8 V (25°C) From: Typ 714, Max 855 To: Typ 737, Max 1100	5
•	Changed r <sub>ON</sub> values for V <sub>INX</sub> = 1.8 V (Full) From: Max 995 To: Max 1300	5
•	Changed r <sub>ON</sub> values for V <sub>INX</sub> = 1.62 V (25°C) From: Typ 830, Max 950 To: Typ 848, Max 1300	5

Product Folder Links: TPS22960



# 5 Pin Configuration and Functions





#### **Pin Functions**

	PIN		1/0	DESCRIPTION
NAME	SOT	UQFN	I/O	DESCRIPTION
V <sub>IN1</sub>	1	1	I	Switch 1 input; bypass this input with a ceramic capacitor to GND
ON1	2	2	I	Switch 1 control input, active high. Do not leave floating.
ON2	3	7	I	Switch 2 control input, active high. Do not leave floating.
V <sub>IN2</sub>	4	8	ı	Switch 2 input; bypass this input with a ceramic capacitor to GND
V <sub>OUT2</sub>	5	5	0	Switch 2 output
GND	6	6	_	Ground
SR	7	3	I	Slew rate control pin. SR = GND translates into a 75-μs rise time; SR = high translates into a 660-μs rise time
V <sub>OUT1</sub>	8	4	0	Switch 1 output

# 6 Specifications

#### 6.1 Absolute Maximum Ratings

(see (1))

		MIN	MAX	UNIT
$V_{IN}$	Input voltage	-0.3	6	V
V <sub>OUT</sub>	Output voltage		$V_{IN} + 0.3$	V
$V_{ON}$	Input voltage	-0.3	6	V
I <sub>MAX</sub>	Maximum continuous switch current		0.5	Α
T <sub>A</sub>	Operating free-air temperature	-40	85	°C
TJ	Maximum junction temperature		125	°C
T <sub>stg</sub>	Storage temperature	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### 6.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2)	1000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



# 6.3 Recommended Operating Conditions

			MIN	MAX	UNIT
$V_{IN}$	Input voltage		1.62	5.5	V
$V_{OUT}$	Output voltage			$V_{IN}$	V
.,	High level inner welterner ONA ONO CD	V <sub>INx</sub> = 3.0 V to 5.5 V	1.5	5.5	
V <sub>IH</sub>	High-level input voltage: ON1, ON2, SR $V_{\text{INx}} = 1.62 \text{ V to } 3.0$	V <sub>INx</sub> = 1.62 V to 3.0 V	1.4	5.5	V
.,	Law level input valta no. ONA ONO CD	V <sub>INx</sub> = 3.0 V to 5.5 V		0.5	
$V_{IL}$	Low-level input voltage: ON1, ON2, SR	V <sub>INx</sub> = 1.62 V to 3.0 V		0.4	V
C <sub>IN</sub>	Input capacitor		1 <sup>(1)</sup>		μF

<sup>(1)</sup> See Application Information

# 6.4 Thermal Information

			TPS22960		
	THERMAL METRIC <sup>(1)</sup>	DCN (SOT)	RSE (UQFN)	UNIT	
		8 PINS	8 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	254	124	°C/W	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	122	67	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	181	31.5	°C/W	
ΨЈТ	Junction-to-top characterization parameter	22	2.9	°C/W	
$\Psi_{JB}$	Junction-to-board characterization parameter	178	31.5	°C/W	
R <sub>0</sub> JC(bot)	Junction-to-case (bottom) thermal resistance	_	_	°C/W	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics (SPRA953).



## 6.5 Electrical Characteristics

 $V_{IN}$  = 1.62 V to 5.5 V,  $T_A$  = -40°C to 85°C (unless otherwise noted)

	PARAMETER	TEST CONDITION	S	T <sub>A</sub>	MIN TYP <sup>(1)</sup>	MAX	UNIT
			V <sub>INx</sub> = 5.5 V	Full	0.64	2	
	Quiescent current	I -0 V -V	$V_{INx} = 3.3 V$	Full	0.35	1.2	
I <sub>IN</sub>	(each switch)	$I_{OUTx} = 0, V_{INx} = V_{ON}$	V <sub>INx</sub> = 2.5 V	Full	0.24	0.8	μA
			$V_{INx} = 1.8 \text{ V}$	Full	0.15	0.5	
			$V_{INx} = 5.5 V$	Full	0.47	3.6	
	OFF-state supply	V CND V Open	$V_{INx} = 3.3 V$	Full	0.25	1.8	
I <sub>IN(OFF)</sub>	current (each switch)	$V_{ON} = GND, V_{OUTx} = Open$	$V_{INx} = 2.5 V$	Full	0.18	1.3	μA
			V <sub>INx</sub> = 1.8 V	Full	0.11	0.9	
			V 5.5.V	25°C	342	400	<del>-</del> -
			$V_{INx} = 5.5 V$	Full		465	
			V <sub>INx</sub> = 3.3 V	25°C	435	500	
				Full		595	
_	ON-state resistance	1 200 m A	V 2.5.V	25°C	523	620	<b>~</b> 0
r <sub>ON</sub>	(each switch)	$I_{OUT} = -200 \text{ mA}$	$V_{INx} = 2.5 V$	Full		720	mΩ
			V 4.9.V	25°C	737	1100	
			$V_{INx} = 1.8 V$	Full		1300	
			V 4.62.V	25°C	848	1300	
			$V_{INx} = 1.62 V$	Full		1500	
r <sub>PD</sub>	Output pulldown resistance	$V_{IN} = 3.3 \text{ V}, V_{ON} = 0, I_{OUT} = 30 \text{ mA}$		25°C	85	120	Ω
I <sub>ON</sub>	ON-state input leakage current	V <sub>ON</sub> = 1.62 V to 5.5 V or GND		Full		0.25	μΑ

<sup>(1)</sup> Typical values are at  $T_A = 25$ °C.

# 6.6 Switching Characteristics

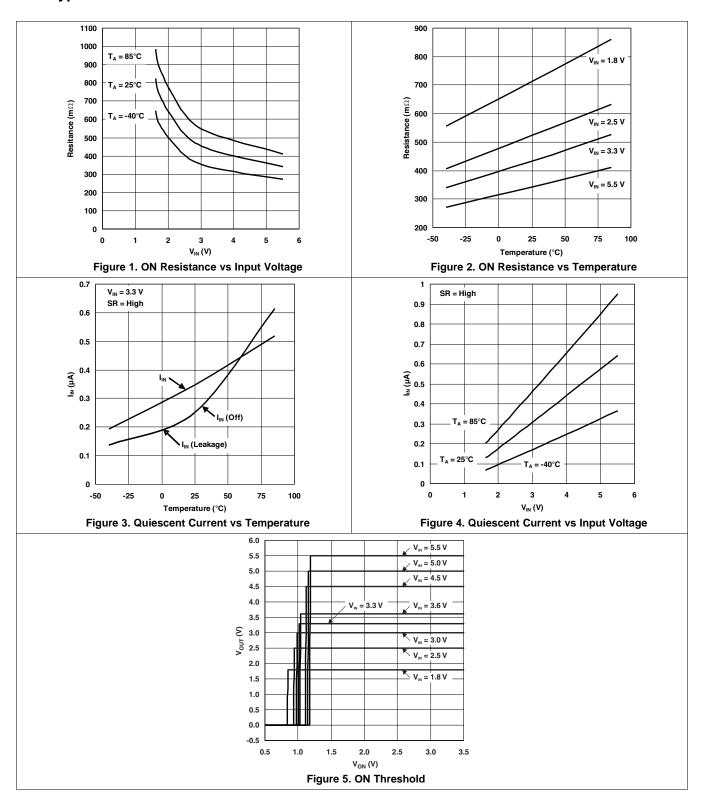
 $\rm V_{IN}$  = 3.3 V,  $\rm T_A$  = 25°C, RL\_CHIP = 85  $\Omega$  (unless otherwise noted)

	PARAMETER	TEST CONDI	MIN TYP <sup>(1)</sup> MAX	UNIT	
	Turn-ON time	B 33 0 C 04 UE	SR = V <sub>IN</sub>	635	
t <sub>ON</sub>	rum-on time	$R_L = 33 \Omega, C_L = 0.1 \mu F$	SR = GND	67	μs
	Turn-OFF time	B 33 0 C 04 UE	SR = V <sub>IN</sub>	4.5	
t <sub>OFF</sub>	Turn-OFF time	$R_L = 33 \Omega, C_L = 0.1 \mu F$	SR = GND	4.2	μs
	N wine time	B 22.0.0 0.4.1.5	SR = V <sub>IN</sub>	660	
ι <sub>r</sub>	V <sub>OUT</sub> rise time	$R_L = 33 \ \Omega, \ C_L = 0.1 \ \mu F$	SR = GND	75	μs
	\/ fall time	D 22.0.0 04.1F	SR = V <sub>IN</sub>	4.5	
t <sub>f</sub>	V <sub>OUT</sub> fall time	$R_L = 33 \Omega, C_L = 0.1 \mu F$	SR = GND	4.5	μs

<sup>(1)</sup> Typical values are at the specified  $V_{IN}$  = 3.3 V and  $T_A$  = 25°C



# 6.7 Typical DC Characteristics

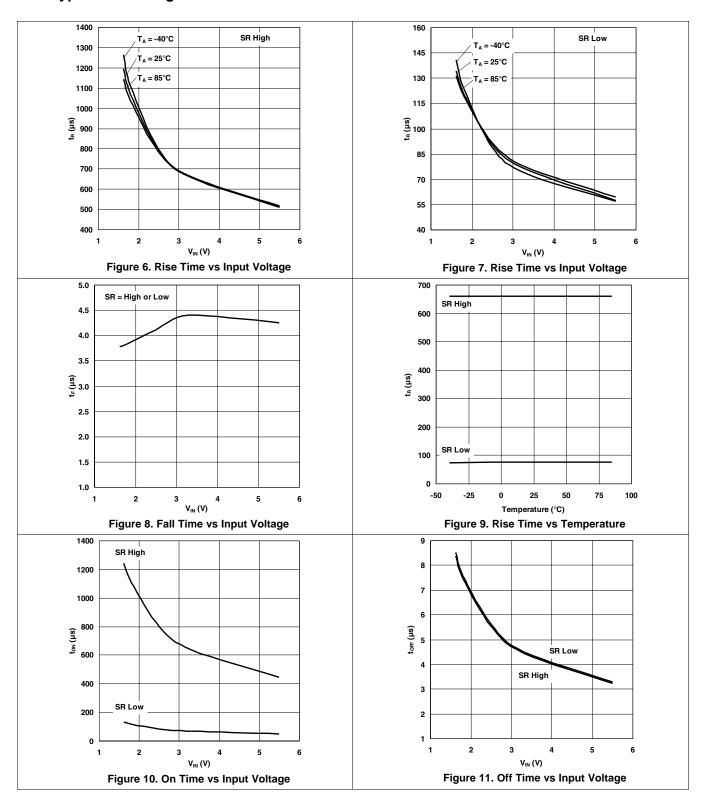


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# 6.8 Typical Switching Characteristics

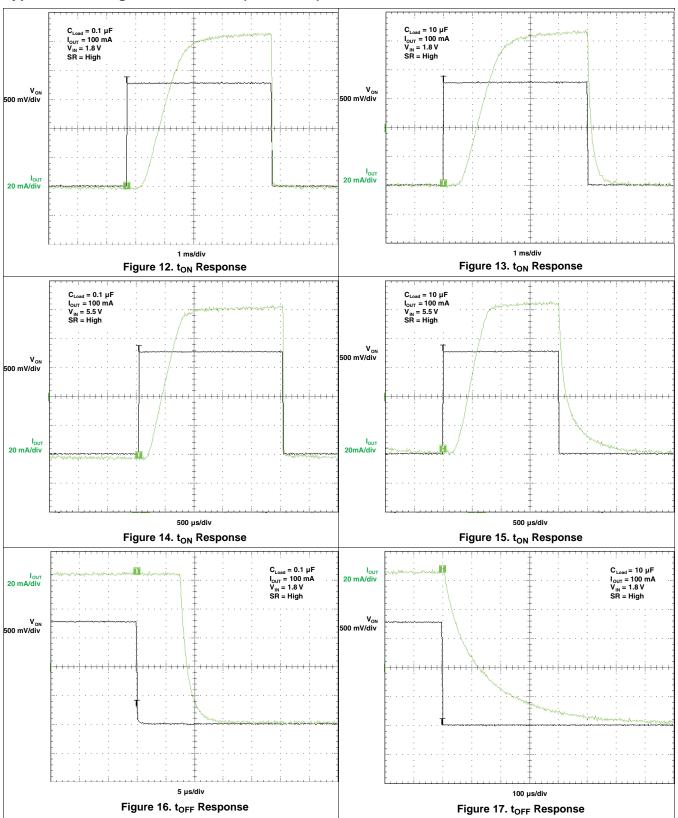


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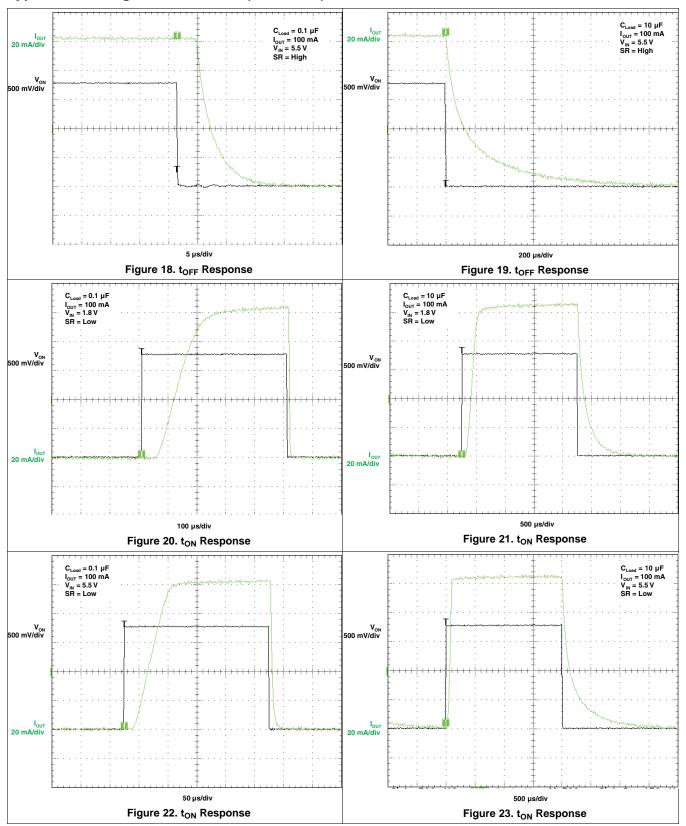
# TEXAS INSTRUMENTS

# **Typical Switching Characteristics (continued)**



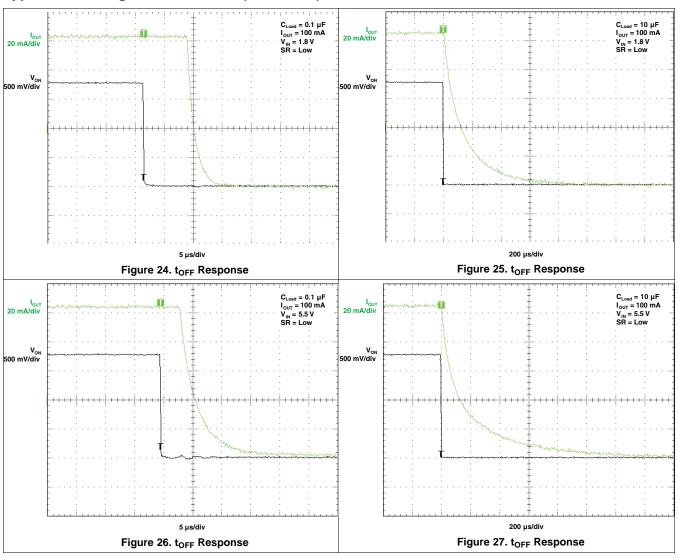


# **Typical Switching Characteristics (continued)**



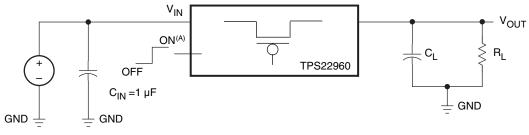
# TEXAS INSTRUMENTS

# **Typical Switching Characteristics (continued)**

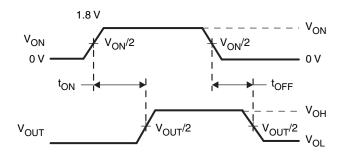


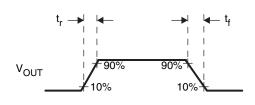


# 7 Parameter Measurement Information



**TEST CIRCUIT** 





 $t_{\mbox{ON}}/t_{\mbox{OFF}}$  WAVEFORMS

A.  $t_{rise}$  and  $t_{fall}$  of the control signal is 100 ns.

Figure 28. Test Circuit and  $t_{\text{ON}}/t_{\text{OFF}}$  Waveforms

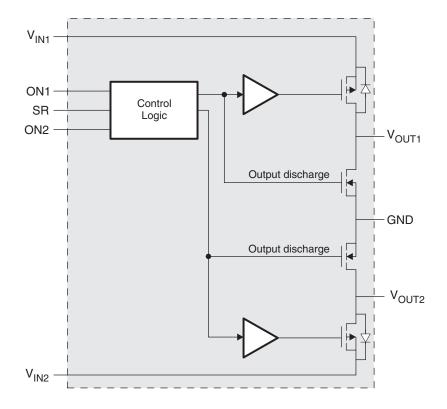


# 8 Detailed Description

#### 8.1 Overview

The TPS22960 is a dual-channel load switch. The two channels can be independently controlled using the ONx pins. Each channel has an  $85-\Omega$  quick discharge resistance from  $V_{OUTX}$  to GND when disabled. A single control pin (SR) is used to set the slew rate for both channels..

# 8.2 Functional Block Diagram



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#### 8.3 Feature Description

This section will discuss the features of the TPS22960 which have been summarized in Table 1.

**Table 1. Feature Summary** 

DEVICE	r <sub>ON</sub> AT 3.3 V (TYP)	SLEW RATE AT 3.3 V (TYP)	QUICK OUTPUT DISCHARGE <sup>(1)</sup>	MAX OUTPUT CURRENT	ENABLE
TPS22960	435 mΩ	75 μs with SR = low 660 μs with SR = high	Yes	500 mA	Active High

<sup>(1)</sup> This feature discharges the output of the switch to ground through an  $85-\Omega$  resistor, preventing the output from floating.

#### 8.3.1 Output Slew Rate (SR) Control

The slew rate (rise time) of the device is internally controlled in order to avoid inrush current, and it can be slowed down if needed using the SR pin. At 3.3 V, TPS22960 features a 75-µs rise time with the SR pin tied to ground, and a 660-µs rise time with the SR pin tied high. Both channels will have the same slew rate set by the SR pin.

## 8.3.2 Quick Output Discharge (QOD)

Each channel of the TPS22960 includes an independent QOD feature. When the channel is disabled, a discharge resistor is connected between VOUTx and GND. This resistor has a typical value of 85  $\Omega$  and prevents the output from floating while the switch is disabled.

#### 8.4 Device Functional Modes

**Table 2. Configurable Logic Function Table** 

ONx	V <sub>INx</sub> TO V <sub>OUTx</sub>	V <sub>OUTx</sub> TO GND
L	OFF	ON
Н	ON	OFF



## 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

#### 9.1 Application Information

#### 9.1.1 ON/OFF Control

The ON pin controls the state of the switch. Activating ON continuously holds the switch in the on state, as long as there is no fault. ON is active HI and has a low threshold, making it capable of interfacing with low voltage signals. The ON pin is compatible with standard GPIO logic threshold. It can be used with any microcontroller with 1.2-V, 1.8-V, 2.5-V, or 3.3-V GPIOs.

#### 9.1.2 Input Capacitor

To limit voltage drop or voltage transients, sufficient capacitance needs to be placed on the input side of the load switch (from  $V_{IN}$  to GND). In most cases, a 1- $\mu$ F ceramic capacitor,  $C_{IN}$ , placed close to the pins is usually sufficient. However, when switching heavy capacitive loads, higher values of  $C_{IN}$  may be needed to prevent the system supply voltage from dropping.

#### 9.1.3 Output Capacitor

The integral body diode in the PMOS switch will allow reverse current flow if  $V_{OUT}$  exceeds  $V_{IN}$ . A  $C_L$  greater than  $C_{IN}$  can cause  $V_{OUT}$  to exceed  $V_{IN}$  if the system supply is removed. In the case where the system supply could be removed and reverse current is a concern, a  $C_{IN}$  greater than  $C_L$  is recommended.

#### 9.2 Typical Application

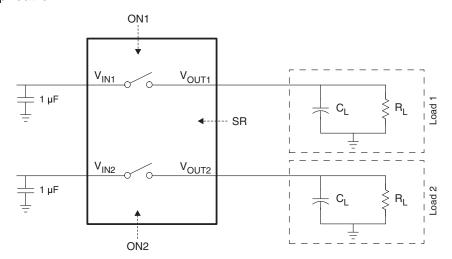


Figure 29. Typical Application Schematic

Product Folder Links: TPS22960

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## **Typical Application (continued)**

#### 9.2.1 Design Requirements

For this design example, use input parameters in Table 3.

**Table 3. Design Parameters** 

PARAMETER	EXAMPLE VALUE
V <sub>IN</sub>	3.3 V
$C_L$	22 μF
Maximum acceptable inrush current	200 mA

#### 9.2.2 Detailed Design Procedure

#### 9.2.2.1 Inrush Current

When the switch is enabled, the output capacitors must be charged up from 0 V to the set value (in this example, 3.3 V). This charge arrives in the form of inrush current. Inrush current can be calculated using the following equation:

Inrush Current = 
$$C \times dV / dt$$
 (1)

Where:

C = output capacitance

dV = output voltage

dt = rise time

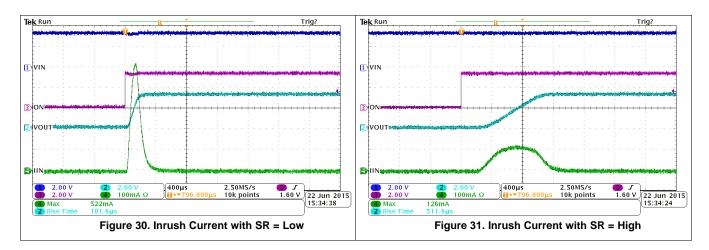
The TPS22960 offers selectable rise time control for  $V_{OUT}$ . This feature allows the user to control the inrush current during turnon. Equation 1 can be used to find the required rise time to limit the inrush current to the design requirements

$$200 \text{ mA} = 22 \mu\text{F} \times (3.3 \text{ V} \times 80\%) / \text{dt}$$
 (2)

 $dt = 290 \mu s (4)$ 

To ensure an inrush current of less than 200 mA, SR must be set high for a rise time greater than 290 µs. The following application curves show the different inrush for each SR setting in this design example.

#### 9.2.3 Application Curves





## 10 Power Supply Recommendations

The device is designed to operate from an input voltage range of 1.62 V to 5.5 V. The power supply should be well-regulated and placed as close to the device terminals as possible. It must be able to withstand all transient and load current steps. In most situations, using an input capacitance of 1  $\mu$ F is sufficient to prevent the supply voltage from dipping when the switch is turned on. In cases where the power supply is slow to respond to a large transient current or large load current step, additional bulk capacitance may be required on the input

The requirements for larger input capacitance can be mitigated by selecting the slower slew rate +SR=high. This will cause the load switch to turn on more slowly and limit the inrush current.

## 11 Layout

# 11.1 Layout Guidelines

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effects that parasitic trace inductances may have on normal and short-circuit operation. Using wide traces for  $VI_N$ ,  $V_{OUT}$ , and GND will help minimize the parasitic electrical effects along with minimizing the case to ambient thermal impedance.

Product Folder Links: TPS22960

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# 11.2 Layout Example

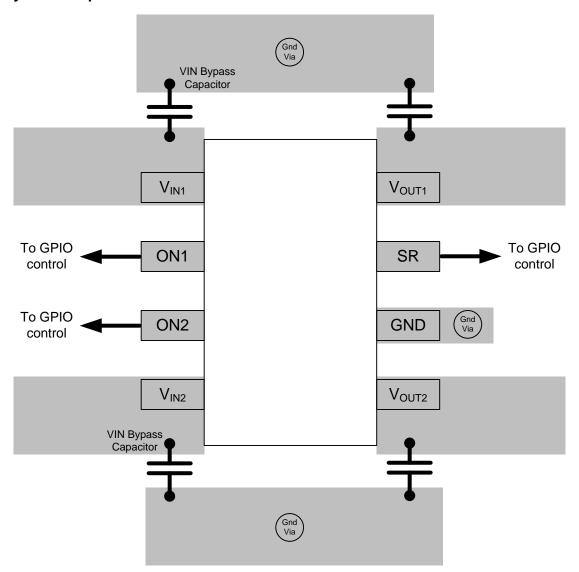


Figure 32. DCN Package Layout



# **Layout Example (continued)**

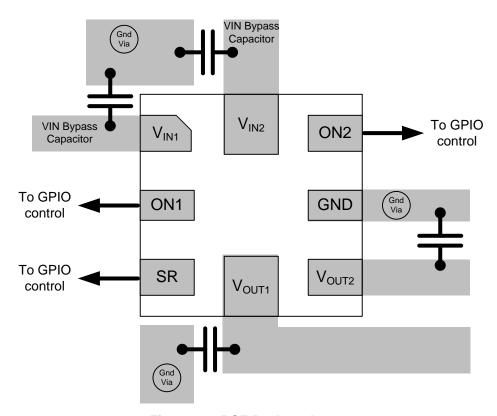


Figure 33. RSE Package Layout



# 12 Device and Documentation Support

#### 12.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.2 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

#### 12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

# 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



# PACKAGE OPTION ADDENDUM

17-Feb-2016

#### **PACKAGING INFORMATION**

www.ti.com

Orderable Device	Status	Package Type	_	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TPS22960DCNR	ACTIVE	SOT-23	DCN	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(NFRO ~ NFRR)	Samples
TPS22960RSER	ACTIVE	UQFN	RSE	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	72	Samples
TPS22960RSET	ACTIVE	UQFN	RSE	8	250	Green (RoHS & no Sb/Br)	CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	72	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE OPTION ADDENDUM**

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continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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# PACKAGE MATERIALS INFORMATION

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# TAPE AND REEL INFORMATION





Α0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

All differsions are norminal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS22960DCNR	SOT-23	DCN	8	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
TPS22960DCNR	SOT-23	DCN	8	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS22960RSER	UQFN	RSE	8	3000	180.0	8.4	1.7	1.7	0.7	4.0	8.0	Q2
TPS22960RSET	UQFN	RSE	8	250	180.0	8.4	1.6	1.6	0.66	4.0	8.0	Q2

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\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS22960DCNR	SOT-23	DCN	8	3000	202.0	201.0	28.0
TPS22960DCNR	SOT-23	DCN	8	3000	203.0	203.0	35.0
TPS22960RSER	UQFN	RSE	8	3000	202.0	201.0	28.0
TPS22960RSET	UQFN	RSE	8	250	202.0	201.0	28.0

DCN (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Package outline exclusive of metal burr & dambar protrusion/intrusion.
- D. Package outline inclusive of solder plating.
- E. A visual index feature must be located within the Pin 1 index area.
- F. Falls within JEDEC MO-178 Variation BA.
- G. Body dimensions do not include flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.



DCN (R-PDSO-G8)

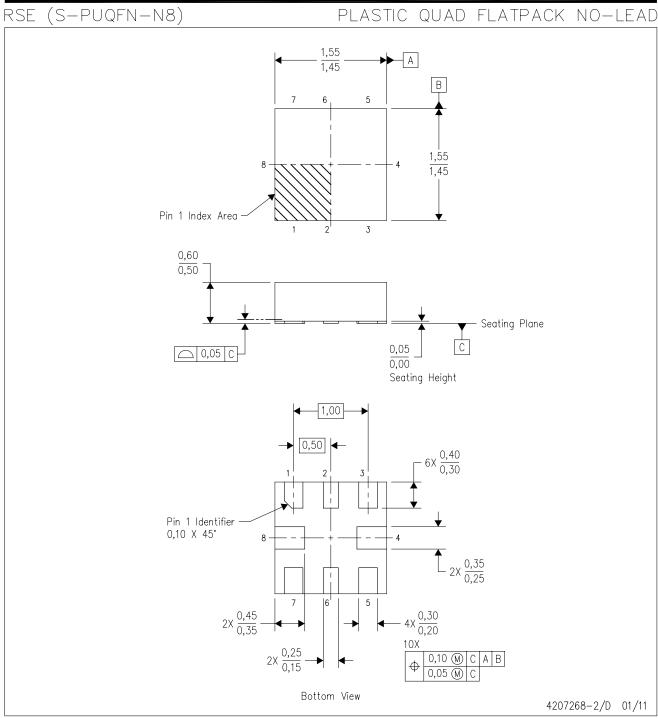
PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





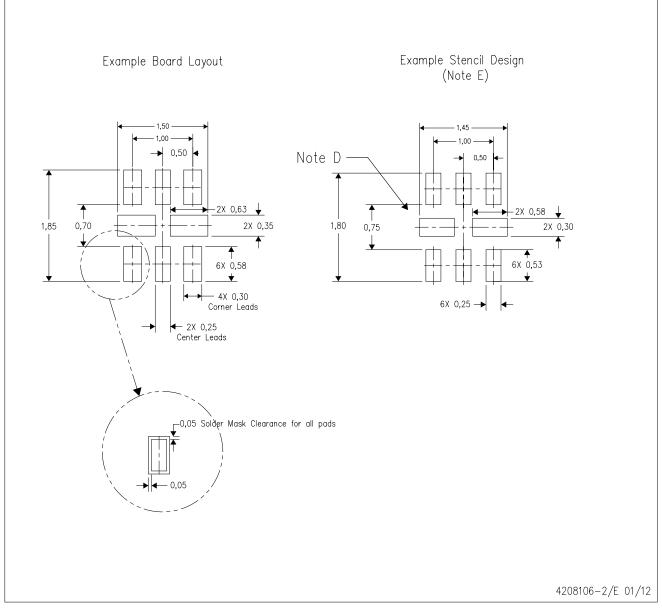
NOTES: All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
  C. QFN (Quad Flatpack No-Lead) package configuration.
  D. This package complies to JEDEC MO-288 variation UECD.



# RSE (S-PUQFN-N8)

## PLASTIC QUAD FLATPACK NO-LEAD



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
  - E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
  - F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
  - G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



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